

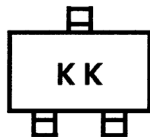
TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK2825

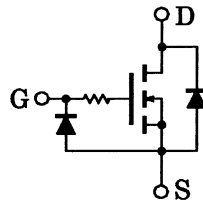
For Portable Equipment
High Speed Switch Applications
Analog Switch Applications

- High input impedance
- 1.5 V gate drive
- Low gate threshold voltage: $V_{th} = 0.5 \sim 1.0$ V
- Small package

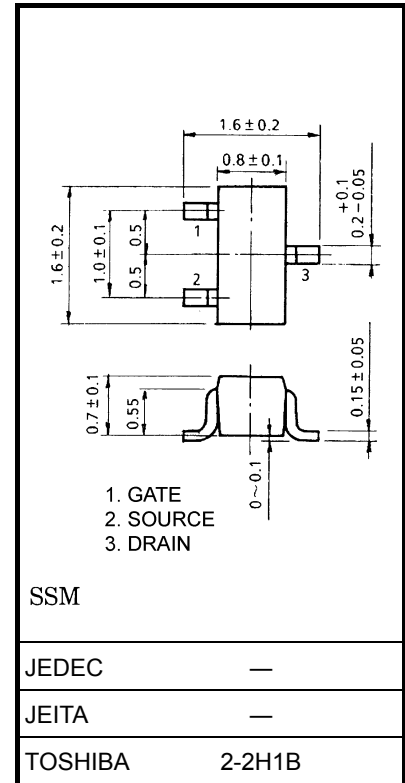
Marking



Equivalent Circuit



Unit: mm



Weight: 2.4 mg (typ.)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	20	V
Gate-source voltage	V_{GSS}	10	V
DC drain current	I_D	100	mA
Drain power dissipation	P_D	100	mW
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: This transistor is electrostatic sensitive device.

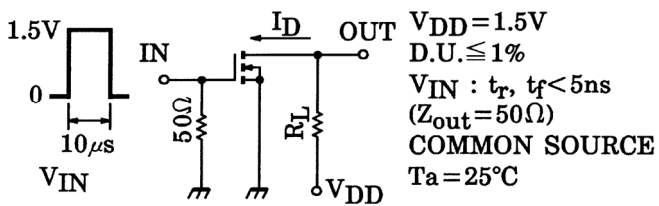
Please handle with caution.

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = 10\text{ V}, V_{DS} = 0$	—	—	1	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 100\ \mu\text{A}, V_{GS} = 0$	20	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = 20\text{ V}, V_{GS} = 0$	—	—	1	μA
Gate threshold voltage	V_{th}	$V_{DS} = 1.5\text{ V}, I_D = 0.1\text{ mA}$	0.5	—	1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 1.5\text{ V}, I_D = 10\text{ mA}$	35	70	—	mS
Drain-source ON resistance 1	$R_{DS(ON)1}$	$I_D = 1\text{ mA}, V_{GS} = 1.2\text{ V}$	—	15	50	Ω
Drain-source ON resistance 2	$R_{DS(ON)2}$	$I_D = 10\text{ mA}, V_{GS} = 1.5\text{ V}$	—	10	40	Ω
Drain-source ON resistance 3	$R_{DS(ON)3}$	$I_D = 10\text{ mA}, V_{GS} = 2.5\text{ V}$	—	7	28	Ω
Input capacitance	C_{iss}	$V_{DS} = 1.5\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	12	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DS} = 1.5\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	3.4	—	pF
Output capacitance	C_{oss}	$V_{DS} = 1.5\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	12	—	pF
Switching time	Turn-on time	$V_{DD} = 1.5\text{ V}, I_D = 10\text{ mA},$ $V_{GS} = 0 \sim 1.5\text{ V}$	—	0.35	—	μs
	Turn-off time		—	0.2	—	

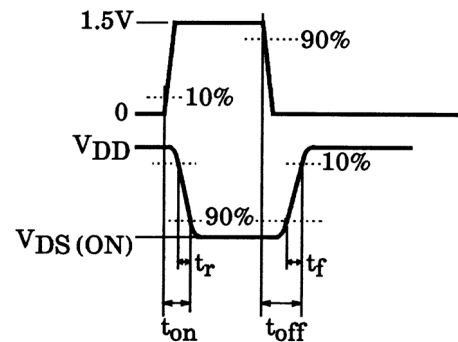
Switching Time Test Circuit

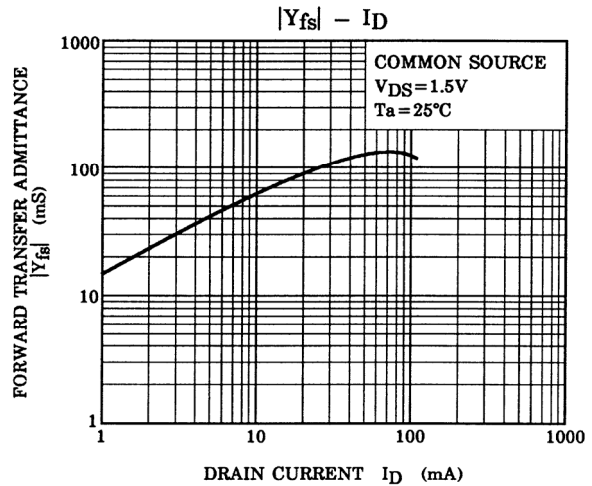
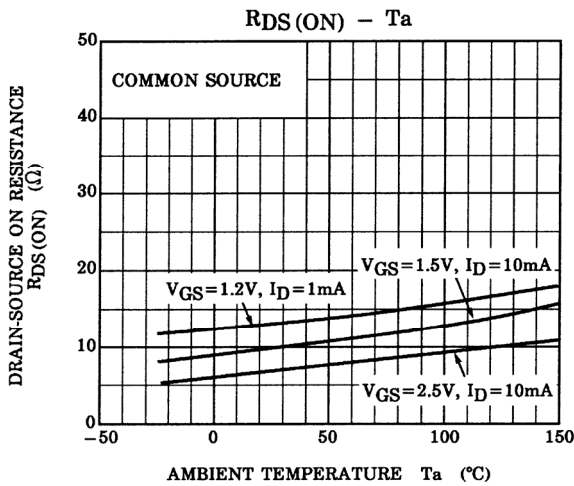
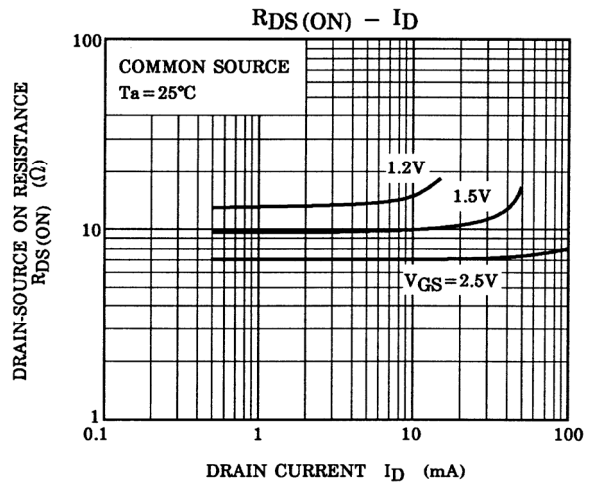
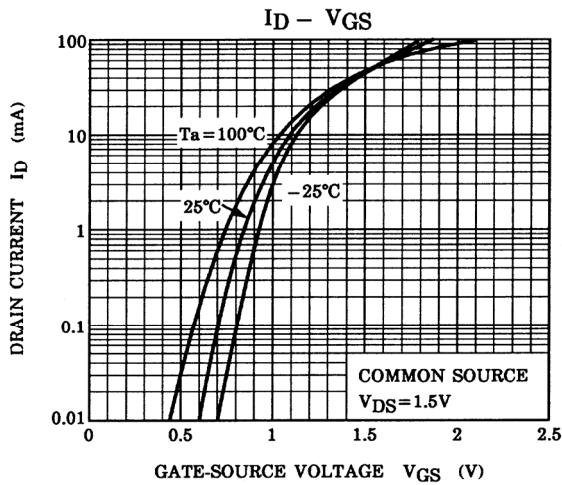
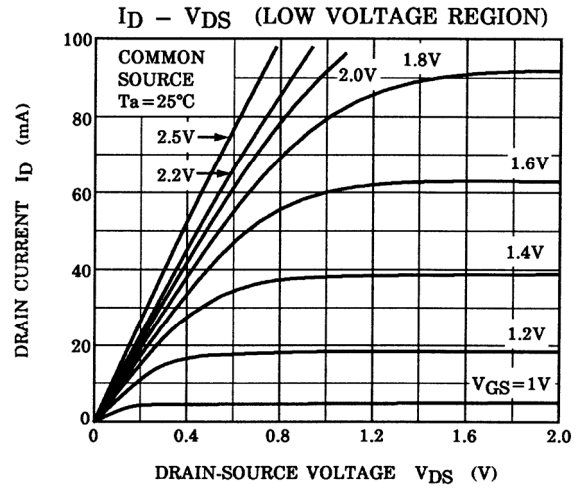
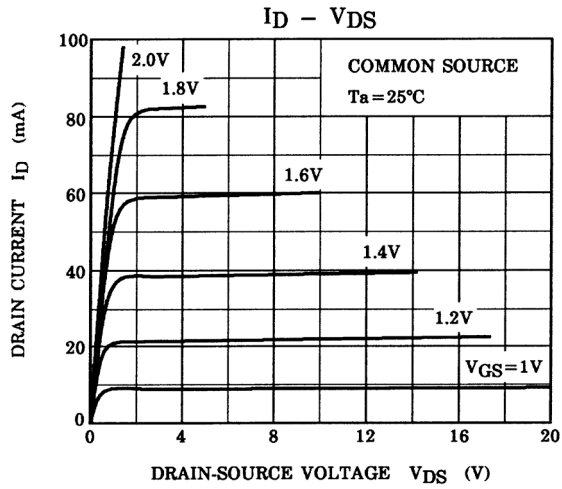
(1) Test circuit

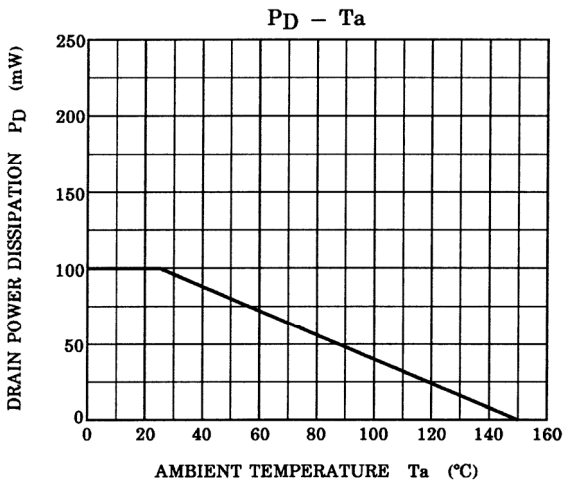
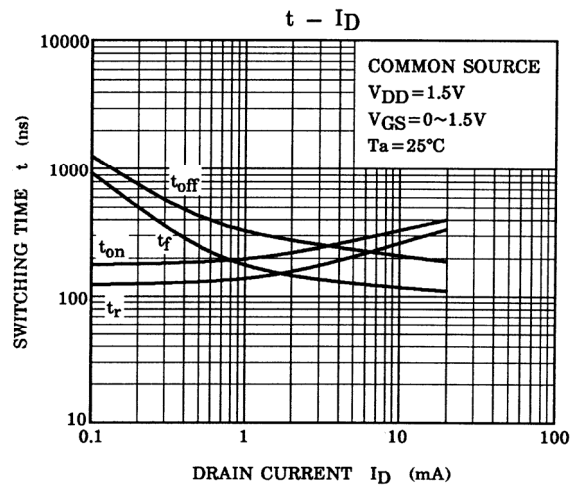
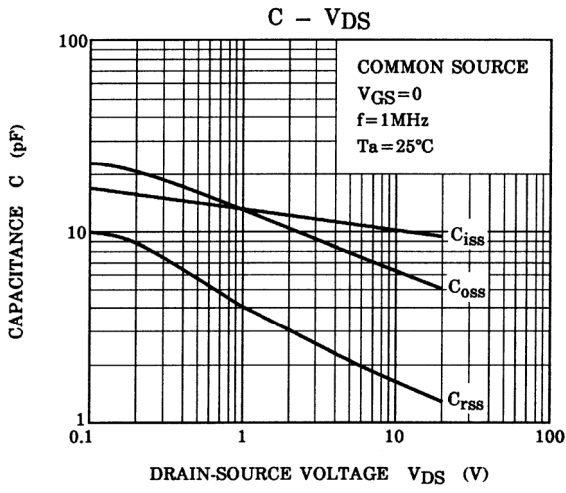


(2) V_{IN}
 V_{GS}

(3) V_{OUT}
 V_{DS}







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20070701-EN GENERAL

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